

AD-A192 129

SYNTHESIS AND CHARACTERIZATION OF NEOPENTYL GALLIUM
COMPOUNDS(U) STATE UNIV OF NEW YORK AT BUFFALO DEPT OF
CHEMISTRY D T BEACHLEY ET AL. 25 FEB 88 TR-13

1/1

UNCLASSIFIED

N00014-87-K-0266

F/G 7/3

NL





1.0
1.1
1.25
1.4
1.6
1.8
2.0
2.2
2.5
2.8
3.15
3.6
4.0
4.5



SECURITY CLASSIFICATION OF THIS PAGE

AD-A192 129

REPORT DOCUMENTA

1a. REPORT SECURITY CLASSIFICATION Unclassified			1b. RESTRICTIVE MARKINGS		
2a. SECURITY CLASSIFICATION AUTHORITY DTIC ELECTED MAR 07 1988			3. DISTRIBUTION / AVAILABILITY OF REPORT Distribution list enclosed		
2b. DECLASSIFICATION / DOWNGRADING SCHEDULE			4. PERFORMING ORGANIZATION REPORT NUMBER(S) 19		
4a. NAME OF PERFORMING ORGANIZATION State University of New York at Buffalo			6b. OFFICE SYMBOL (If applicable)		7a. NAME OF MONITORING ORGANIZATION Office of Naval Research
6a. ADDRESS (City, State, and ZIP Code) Department of Chemistry Buffalo, NY 14214			7b. ADDRESS (City, State, and ZIP Code) Department of the Navy Arlington, VA 22217		
8a. NAME OF FUNDING / SPONSORING ORGANIZATION Office of Naval Research		8b. OFFICE SYMBOL (If applicable)		9. PROCUREMENT INSTRUMENT IDENTIFICATION NUMBER N00014-87-K-0266	
8c. ADDRESS (City, State, and ZIP Code) Department of the Navy Arlington, VA 22217		10. SOURCE OF FUNDING NUMBERS		WORK UNIT ACCESSION NO 4135002	
PROGRAM ELEMENT NO.		PROJECT NO.		TASK NO.	
11. TITLE (Include Security Classification) Synthesis and Characterization of Neopentylgallium Compounds					
12. PERSONAL AUTHOR(S) O. T. Beachley, Jr. and J. C. Pazik					
13a. TYPE OF REPORT Technical Report		13b. TIME COVERED FROM TO		14. DATE OF REPORT (Year, Month, Day) 25 February 1988	
15. PAGE COUNT 16					
16. SUPPLEMENTARY NOTATION To be published in <u>Organometallics</u>					
17. COSATI CODES			18. SUBJECT TERMS (Continue on reverse if necessary and identify by block number)		
FIELD	GROUP	SUB-GROUP	Organogallium chemistry, neopentylgallium compounds, organogallium halogen compounds, trimethylsilylmethylgallium halogen compounds.		
19. ABSTRACT (Continue on reverse if necessary and identify by block number)					
<p>The series of neopentylgallium compounds, $\text{Ga}(\text{CH}_2\text{CMe}_3)_3$, $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Br}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{I}_2$ have been prepared by very facile, high yield routes, have been easily purified and have been fully characterized. The new compound $\text{Ga}(\text{CH}_2\text{CMe}_3)_3$ is a nonpyrophoric liquid which exists as monomeric, three-coordinate gallium species in benzene solution. Cryoscopic molecular weight studies indicate that $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2$ and $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Br}_2$ are dimeric in benzene solution. Consequently, it is noteworthy that an equimolar mixture of $[\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}]_2$ and $[\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2]_2$ does not undergo a rapid</p>					
20. DISTRIBUTION / AVAILABILITY OF ABSTRACT <input checked="" type="checkbox"/> UNCLASSIFIED/UNLIMITED <input type="checkbox"/> SAME AS RPT. <input type="checkbox"/> DTIC USERS			21. ABSTRACT SECURITY CLASSIFICATION Unclassified		
22a. NAME OF RESPONSIBLE INDIVIDUAL O. T. Beachley, Jr.			22b. TELEPHONE (Include Area Code) 716-831-3266		22c. OFFICE SYMBOL

19. ABSTRACT (continued)

exchange reaction at room temperature as four ^1H NMR lines are observed. A comparison of the properties of the neopentyl- and trimethylsilylmethylgallium derivatives suggest that the neopentyl group has larger steric effects and stronger electron withdrawing properties than the corresponding trimethylsilylmethyl substituents.



Accession For	
NTIS GRA&I	<input checked="checked" type="checkbox"/>
DTIC TAB	<input type="checkbox"/>
Unannounced	<input type="checkbox"/>
Justification	
By	
Distribution/	
Availability Codes	
Dist	Avail and/or Special
A-1	

OFFICE OF NAVAL RESEARCH
Contract N-00014-87-K-0266
R&T Code 4135002
TECHNICAL REPORT NO. 19

Synthesis and Characterization of Neopentylgallium Compounds

by

O. T. Beachley, Jr. and J. C. Pazik

Prepared for Publication

in

Organometallics

State University of New York at Buffalo
Department of Chemistry
Buffalo, New York 14214

25 February 1988

Reproduction in whole or in part is permitted for
any purpose of the United States Government

*This document has been approved for public release
and sale; its distribution is unlimited

(Contribution from the Department of Chemistry, State University of New York at Buffalo, Buffalo, NY 14214)

Synthesis and Characterization of Neopentylgallium Compounds

by

O. T. Beachley, Jr. and J. C. Pazik

Abstract

The series of neopentylgallium compounds, $\text{Ga}(\text{CH}_2\text{CMe}_3)_3$, $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Br}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{I}_2$, have been prepared by very facile, high yield routes, have been easily purified and have been fully characterized. The new compound $\text{Ga}(\text{CH}_2\text{CMe}_3)_3$ is a nonpyrophoric liquid which exists as monomeric, three-coordinate gallium species in benzene solution. Cryoscopic molecular weight studies indicate that $\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}$, $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2$ and $\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Br}_2$ are dimeric in benzene solution. Consequently, it is noteworthy that an equimolar mixture of $[\text{Ga}(\text{CH}_2\text{CMe}_3)_2\text{Cl}]_2$ and $[\text{Ga}(\text{CH}_2\text{CMe}_3)\text{Cl}_2]_2$ does not undergo a rapid exchange reaction at room temperature as four ^1H NMR lines are observed. A comparison of the properties of the neopentyl- and trimethylsilylmethyl-gallium derivatives suggest that the neopentyl group has larger steric effects and stronger electron withdrawing properties than the corresponding trimethylsilylmethyl substituents.

Introduction

The utilization of compound semiconductors for electronic and optical devices can be related to the development of epitaxial growth techniques.¹ The technique of choice for preparing compound semiconductors such as GaAs, GaP and GaSb is organometallic vapor phase epitaxy or organometallic chemical vapor deposition. Since only a surprisingly few organogallium compounds, GaMe₃ and GaEt₃, are readily available as gallium sources, our research program has been directed toward the synthesis and characterization of new organogallium compounds. In order for a gallium compound to be a useful gallium source, the compound should be readily prepared and easily purified as well as be a volatile liquid with excellent thermal stability at room temperature. In this paper, we report the synthesis and characterization of a series of organogallium compounds which incorporate the neopentyl (CH₂CMe₃=Np) group including GaNp₃, GaNp₂Cl, GaNp₂Br, GaNpCl₂ and GaNpI₂. These neopentylgallium derivatives are of chemical interest because the bulky neopentyl substituent with no β -hydrogen atoms might introduce unusual chemical properties. Furthermore, direct comparisons between corresponding neopentyl and trimethylsilylmethyl² derivatives might enhance our understanding of the electronic and steric effects of these organic substituents in organogallium chemistry.

Experimental Section

All compounds described in this investigation were extremely sensitive to oxygen and moisture and were manipulated in a standard vacuum line or in a purified argon atmosphere. All solvents were purified before use. Gallium(III) chloride was purified by sublimation under high vacuum at 70-80°C immediately prior to use. The compound GaI₃ was prepared from gallium

metal and iodine in refluxing toluene, a modification of the method of Tuck and Freeland.³ Neopentyl chloride was purchased from Fairfield Chemical Co. and was distilled prior to use. Elemental analyses were performed by Schwarzkopf Microanalytical Laboratory, Woodside, NY. Infrared spectra of Nujol mulls between CsI plates were recorded by means of a Perkin-Elmer 683 spectrometer. Absorption intensities are reported with the abbreviations v (very strong), s (strong), m (medium), w (weak) and sh (shoulder). The ^1H NMR spectra were recorded at 90MHz by using a Varian Model EM-390 spectrometer. All samples for NMR spectra were contained in sealed NMR tubes. Chemical shifts are reported in δ units (ppm) and are referenced to SiMe_4 as δ 0.00 and benzene as δ 7.13. Melting points were observed in sealed capillaries. Molecular weights were measured cryoscopically in benzene by using an instrument similar to that described by Shriver.⁴

Synthesis of GaNP_3 . In a typical synthetic experiment, the Grignard reagent, NPmgl , was prepared from magnesium turnings (5.802g, 238.6mmol) and freshly distilled neopentyl chloride (24.22g, 227.2mmol) in 100mL of diethyl ether. Even though the magnesium had been activated with iodine without stirring prior to the addition of the neopentyl chloride/ether solution, the reaction mixture was refluxed for 18h. Then a flask charged with 9.58g of freshly sublimed GaCl_3 (54.4mmol) dissolved in 250mL of dry diethyl ether was fitted with a condenser, mechanical stirrer and a pressure equalizing addition funnel. Under a cover of argon the Grignard solution was transferred to the addition funnel and was added to the GaCl_3 solution over a period of 20 min. After the addition was complete, the reaction mixture was stirred at room temperature for 18h. The stirrer, condenser and addition funnel were replaced by stoppers and a Teflon valve/adaptor. The Et_2O was then removed by vacuum distillation at room temperature. The crude

product, a $\text{GaP}_3/\text{Et}_2\text{O}$ mixture, was isolated by vacuum distillation at 125°C into a side arm flask (cooled to -196°C) attached to the reaction flask by means of an 85° bent elbow. The distillation was continued for approximately 5h. The Et_2O was then removed from the crude produce by a simple vacuum distillation at room temperature for 1h. The product was finally purified by vacuum distillation in a short path still at 55°C (0.001mm, dynamic vacuum). Pure GaP_3 was obtained as a colorless, nonpyrophoric liquid (14.0g, 49.6mmol, 91.1% yield based on GaCl_3).

$\text{Ga}(\text{CH}_2\text{CMe}_3)_3$. $^1\text{H NMR}$ (C_6H_6 , δ): 1.06 (s, 27H, $-\text{CMe}_3$) and 1.01 (s, 6H, $-\text{CH}_2-$). IR (neat liquid, cm^{-1}): 2950(vs), 2900(vs), 2860(vs), 2650(w), 1468(s), 1461(s), 1398(m), 1382(m), 1358(vs), 1229(s), 1132(m), 1095(m), 1031(m), 1006(s), 928(w), 909(w), 735(m), 703(m), 610(m), 591(m), 570(m), 460(sh), 450(m), 380(m), 310(m), 287(m). Anal. Calcd.: C, 63.63; H, 11.75. Found: C, 63.64; H, 11.68. Cryoscopic molecular weight, benzene solution, formula weight 283 (obsd. molality, obsd. mol. wt., association): 0.0770, 275, 0.965; 0.0610, 291, 1.03; 0.0510, 304, 1.07. Solubility: soluble in ether, THF, benzene and pentane. Trineopentylgallium(III) does not form stable 1:1 adducts with either THF or Et_2O .

Synthesis of GaP_2Cl . Trineopentylgallium(III) (2.93g, 10.4mmol) was weighed in the dry box into a tared, screw-cap vial and 0.911g of freshly sublimed GaCl_3 (5.18mmol) was placed in a second tarred vial. Both compounds were dissolved in pentane and then were pipetted into a 100mL side arm flask. Each vial was rinsed several times (5-7) with fresh aliquots of pentane to ensure the quantitative transfer of the reagents. The flask was then stoppered, cooled to -196°C and then evacuated. After stirring at room temperature for 18h the slightly cloudy solution was filtered through a fine glass frit. The pentane was removed by vacuum distillation and GaP_2Cl was

obtained as a colorless solid in nearly quantitative yield (3.65g, 14.7mmol, 95.0% yield). The compound was further purified by recrystallization from pentane at -78°C . GaNp_2Cl . mp $70.0-71.5^{\circ}\text{C}$. ^1H NMR (C_6H_6 , δ): 1.10 (s, 18H, $-\text{CMe}_3$) and 1.31 (s, 4H, $-\text{CH}_2-$). IR (Nujol mull, cm^{-1}): 2718(vw), 2380(vw), 2284(vw), 1983(vw), 1736(vw), 1258(sh), 1234(vs), 1142(m), 1100(m), 1018(m), 1002(m), 932(w), 914(vw), 802(vw), 742(m), 725(vs), 704(m), 639(s), 593(w), 459(w), 450(w), 385(w), 360(sh), 298(m). Anal. Calcd.: C, 48.54; H, 8.96. Found: C, 48.44; H, 9.26. Cryoscopic molecular weight, benzene solution, formula weight 247.5 (obsd. molality, obsd. mol. wt., association): 0.0799, 520, 2.10; 0.0608, 510, 2.06; 0.0458, 503, 2.03. Solubility: soluble in pentane, benzene, Et_2O and THF. The compound, GaNp_2Cl , does not form stable 1:1 adducts with either THF or Et_2O .

Synthesis of GaNp_2Br . Reaction of 0.296g of GaBr_3 (0.956mmol) with 0.544g of GaNp_3 (1.92mmol) in pentane solution yielded 0.657g of the colorless crystalline solid, GaNp_2Br (2.25mmol, 78.5% based on the initial amount of gallium). To facilitate the dissolution of GaBr_3 in pentane, a small amount of the pentane solution of GaNp_3 was added to the vial containing the GaBr_3 . This vial was then rinsed several times to ensure the quantitative transfer of the reagents. Purification was as described for GaNp_2Cl .

GaNp_2Br . mp $68.5-70.0^{\circ}\text{C}$. ^1H NMR (C_6H_6 , δ): 1.11 (s, 18H, $-\text{CMe}_3$) and 1.47 (s, 4H, $-\text{CH}_2-$). IR (Nujol mull, cm^{-1}): 1360(vs), 1258(vw), 1233(s), 1140(w), 1098(w), 1015(w), 1000(m), 930(vw), 910(vw), 800(vw), 740(m), 722(s), 696(m), 635(m), 590(vw), 455(w), 383(w), 360(vw), 295(w). Anal. Calcd.: C, 41.15; H, 7.60. Found: C, 40.85; H, 7.45. Cryoscopic molecular weight, benzene solution, formula weight 291.9 (obsd. molality, obsd. mol.

wt., association): 0.0729, 646, 2.21; 0.0593, 650, 2.23; 0.0503, 645, 2.21.

Solubility: soluble in pentane, benzene, THF and Et₂O.

Synthesis of GaNpCl₂. In a typical reaction 1.11g of freshly sublimed GaCl₃ (6.33mmol) was reacted in pentane with 0.897g of GaNp₃ (3.17mmol) to produce 1.72g of pure GaNpCl₂ (8.12mmol, 85.5% yield based on the initial amount of gallium). The compound can be further purified as described for GaNp₂Cl or by vacuum distillation (0.001mm) in a short path still at 71°C. GaNpCl₂. mp 29.0-31.0°C. ¹H NMR (C₆H₆, δ): 0.91 (s, 8H, -CMe₃) and 1.25 (s, 2H, -CH₂-). IR (Nujol mull, cm⁻¹): 3410(vw), 3355(vw), 2720(w), 2675(vw), 2400(vw), 2290(vw), 2110(vw), 2005(vw), 1970(vw), 1868(vw), 1780(vw), 1730(vw), 1550(vw), 1362(vw), 1263(m), 1233(vs), 1140(s), 1098(m), 1015(m), 1002(s), 928(vw), 910(vw), 845(m), 808(m), 729(vs), 631(s), 562(vw), 528(vw), 455(m), 397(vs), 372(vs), 252 (vs). Anal. Calcd.: C, 28.36; H, 5.24. Found: C, 28.36; H, 5.15. Cryoscopic molecular weight, benzene solution, formula weight 211.8 (obsd. molality, obsd. mol. wt., association): 0.0816, 423, 2.00; 0.0591, 422, 1.99; 0.0445, 418, 1.97. Solubility: soluble in pentane, benzene, THF and Et₂O. The compound, GaNpCl₂, formed a stable 1:1 adduct with THF.

Lewis Acidity Studies. The abilities of GaNp₃, GaNp₂Cl and GaNpCl₂ to form Lewis acid-base adducts with NMe₃ have been investigated. In a typical experiment an excess of Lewis base was vacuum distilled onto a weighed quantity of the Lewis acid. After the resulting sample was warmed to room temperature, the excess base was removed. A mass measurement on the resulting product was used to determine the quantity of base which reacted. The mol ratio of the Lewis acid/base which reacted, the melting point of the resulting adduct and the ¹H NMR spectrum were used to support the formation of adducts. (Since THF was used as a solvent, the formation of adducts is

included in sections on the individual compounds.) The following observations for NMe_3 were made.

$\text{Np}_3\text{GaNMe}_3$: $\text{GaNp}_3/\text{NMe}_3$ mol ratio was inconclusive because the adduct appeared slightly volatile at room temperature (possibly related to dissociation). mp $100\text{--}108^\circ\text{C}$; ^1H NMR (C_6H_6 , δ): 0.74 (s, 6.0 H, CH_2), 1.25 (s, 28.0 H, CMe_3), 1.73 (s, 9.0 H, NMe_3).

$\text{ClNp}_2\text{GaNMe}_3$: $\text{GaNp}_2\text{Cl}/\text{NMe}_3$ mol ratio (mass measurements): 1.06; mp $85.7\text{--}88.2^\circ\text{C}$; ^1H NMR (C_6H_6 , δ): 0.71 (s, 4.1 H, CH_2), 1.34 (s, 17.2 H, CMe_3), 1.82 (s, 9.0 H, NMe_3). Resonance for methylene protons is a doublet ($J = 6$ Hz with a 300 MHz Bruker spectrometer).

$\text{Cl}_2\text{NpGaNMe}_3$: $\text{GaNpCl}_2/\text{NMe}_3$ mol ratio (mass measurements): 1.02; mp $61.0\text{--}70.0^\circ\text{C}$, ^1H NMR (C_6H_6 , δ): 0.83 (s, 1.80 H, CH_2), 1.23 (s, 8.23 H, CMe_3), 1.82 (s, 9.0 H, NMe_3).

Synthesis of GaNpI_2 . Because of the low solubility of GaI_3 in pentane, benzene was used as the reaction solvent. A 0.882g sample of GaI_3 (1.956mmol) was transferred as a solid to a 100mL side arm flask and the remaining traces of GaI_3 were rinsed into the flask with an aliquot of benzene. The sample of GaNp_3 (0.277g, 0.978mmol) was dissolved in benzene and transferred into the reaction flask as described in the synthetic procedure for GaNp_2Cl . After stirring for 18h at ambient temperature, the benzene was removed by vacuum distillation to yield a slightly pink, viscous liquid. The final traces of benzene were removed from the product by dissolving the sample in 25mL of pentane and then by removing all volatile components under high vacuum. This process was repeated. The final product GaNpI_2 (0.886g, 2.25mmol) was isolated as a slightly pink solid in 76.5% yield based on the initial amount of gallium present. An analytically pure sample as a pale pink solid was obtained by recrystallization from pentane

at -78°C . GaNpI_2 . mp $72.0\text{--}75.0^{\circ}\text{C}$. ^1H NMR (C_6H_6 , δ): 0.99 (s, 9H, $-\text{CMe}_3$) and 1.90 (s, 2H, $-\text{CH}_2-$). IR (Nujol mull, cm^{-1}): 1363(s), 1262(vw), 1235(vs), 1132(m), 1092(m), 1026(m), 999(m), 928(vw), 910(vw), 833(vw), 809(vw), 743(w), 721(vs), 614(m), 452(w), 383(w), 288(m). Anal. Calcd.: C, 15.22; H, 2.81. Found: C, 15.40; H, 2.97. Solubility: soluble in benzene, pentane and THF. The compound GaNpI_2 forms a stable 1:1 adduct with THF.

Synthesis of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$. The synthesis of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ was as described for the preparation of GaNp_2Cl . The reaction of 0.994g of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ (3.00mmol) with 0.265g of freshly sublimed GaCl_3 (1.51mmol) produced $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ in nearly quantitative yield (1.17g, 4.19mmol, 92.5% yield based on the amount of gallium used). Purification was achieved by recrystallization from pentane at -78°C . $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$. mp $27\text{--}29^{\circ}\text{C}$. ^1H NMR (C_6H_6 , δ): 0.15 (s, 18H, $-\text{SiMe}_3$) and 0.20 (s, 4H, $-\text{CH}_2-$). IR (Nujol mull, cm^{-1}): 2952(vs), 2895(m), 1935(vw), 1868(vw), 1445(w), 1420(sh), 1414(sh), 1403(w), 1353(w), 1302(w), 1259(s), 1245(vs), 1001(s), 958(sh), 850(vs), 825(vs), 758(s), 720(s), 683(m), 622(m), 610(w), 593(m), 579(m), 560(m), 512(w), 228(s). Anal. Calcd.: C, 34.36; H, 7.93. Found: C, 33.99; H, 7.56. Cryoscopic molecular weight, benzene solution, formula weight 279.6 (obsd. molality, obsd. mol. wt., association): 0.0720, 574, 2.05; 0.0542, 570, 2.04; 0.0361, 571, 2.04. Solubility: soluble in pentane, benzene and THF.

Synthesis of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$. The procedure for the synthesis of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$ was similar to that used to prepare GaNp_2Cl . Addition of 0.914g of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ (2.76mmol) to 0.973g of freshly sublimed GaCl_3 (5.53mmol) in pentane solution produced 1.46g of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$ (6.39mmol, 77.2% yield based on the amount of gallium used). The colorless solid,

$\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$, was purified by recrystallization from pentane at -40°C .

$\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$. mp $55.0\text{--}56.8^\circ\text{C}$ (lit. $48.0\text{--}49.0^\circ\text{C}$).² ^1H NMR (C_6H_6 , δ):

0.01 (s, 9, SiMe_3) and 0.14 (s, 2H, $-\text{CH}_2-$). IR (Nujol mull, cm^{-1}):

3790(vw), 3725(vw), 3660(vw), 3498(vw), 2725(w), 2680(w), 2485(vw),

2360(vw), 2100(vw), 2035(vw), 2000(vw), 1945(w), 1875(w), 1810(vw),

1740(vw), 1648(vw), 1578(vw), 1405(s), 1345(vs), 1323(m), 1247(vs),

1020(vs), 1009(vs), 973(m), 837(vs, br), 787(s), 755(vs, br), 720(vs),

688(vs), 662(w), 621(s), 598(vs), 558(vs), 480(vw), 463(w), 380(vs),

350(vs), 298(vs). Anal. Calcd.: C, 21.09; H, 4.87. Found: C, 21.27; H,

5.01. Solubility: soluble in benzene and pentane.

Results and Discussion

A series of neopentylgallium compounds including GaNp_3 , GaNp_2Cl , GaNp_2Br , GaNpCl_2 and GaNpI_2 have been prepared by very facile, high yield routes, have been easily purified and have been fully characterized. The properties of these neopentyl compounds have also been compared with the corresponding trimethylsilylmethyl derivatives. In cases in which the previously reported properties of trimethylsilylmethylgallium derivatives² were inconsistent with those of the corresponding neopentyl derivative, the synthesis and characterization of the trimethylsilylmethylgallium derivative was reinvestigated. The characterization data for the neopentyl derivatives and the reinvestigated trimethylsilylmethyl derivatives included physical properties, elemental analyses, cryoscopic molecular weight measurements, Lewis acid-base studies and infrared and NMR spectra.

Trineopentylgallium(III) has been prepared from GaCl_3 by a typical Grignard reaction in diethylether solution and has been readily isolated by vacuum distillation at 55°C . For the synthetic reaction to be successful a 25% calculated excess of the Grignard reagent over GaCl_3 , assuming complete reaction, was required. Our experimental data suggested that the reaction between the neopentyl chloride and magnesium proceeded to only 75% completion. It is of interest that GaNp_3 is a nonpyrophoric, colorless liquid. In comparison, $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ ² and most other gallium alkyls⁵ are pyrophoric liquids. Molecular weight studies suggest that GaNp_3 exists as monomeric species in benzene solution. In Lewis acidity studies, neither of the oxygen bases Et_2O nor THF formed stable 1:1 adducts with GaNp_3 , whereas THF formed an adduct with $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$. It is also noteworthy that the stronger base NMe_3 forms an apparent adduct with $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ and probably with GaNp_3 . These observations suggest that the neopentyl group

has significantly greater steric effects than does the trimethylsilylmethyl group. Alternatively, electronic effects may be responsible for the increased Lewis acidity of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$. However, the results of our studies in organoaluminum chemistry⁶ suggest that the neopentyl group has stronger electron withdrawing properties and larger steric effects than the trimethylsilylmethyl group.

The neopentylgallium(III) halides GaNp_2X ($\text{X}=\text{Cl}, \text{Br}$) and GaNpY_2 ($\text{Y}=\text{Cl}, \text{I}$) have been prepared by stoichiometric ligand redistribution reactions between GaNp_3 and the appropriate gallium(III) halide. The ligand redistribution reaction has proven to be a convenient method for preparing the neopentylgallium(III) halide compounds provided that stoichiometric quantities of reagents are employed. Excess quantities of either GaNp_3 or the gallium(III) halide will result in the formation of additional inseparable products. Pentane is the solvent of choice for the ligand redistribution reactions involving GaX_3 ($\text{X}=\text{Cl}, \text{Br}$). These gallium halides are soluble in pentane and pentane is easily removed from the nonvolatile reaction products. In contrast, GaI_3 is insoluble in pentane. Therefore, GaNpI_2 was prepared from GaNp_3 and GaI_3 in a 1:2 mol stoichiometry in benzene solution.

The neopentylgallium(III) halides have been fully characterized. The compounds GaNpCl_2 , GaNp_2Cl and GaNp_2Br are colorless solids whereas GaNpI_2 is a light pink solid at room temperature. Neopentylgallium(III) dichloride has a low melting point ($29.0\text{--}31.0^\circ\text{C}$). Since the melting point is only slightly above room temperature, the compound has been observed to exist as either a crystalline solid, a liquid or more commonly a sticky solid. In order to minimize the problems associated with handling a sticky solid, samples of GaNpCl_2 were heated to form a mobile liquid prior to entry into

the dry box. It is of experimental importance that heated samples remained liquid for a reasonable length of time, about one hour or more, before crystallization. Cryoscopic molecular weight measurements indicate that the neopentylgallium(III) halide compounds (GaNp_2Cl , GaNp_2Br and GaNpCl_2) are dimeric in benzene solution. The most likely structure for a dimeric molecule of this type would involve halogen donor-acceptor bridge bonds. The apparent existence of halogen bridge bonds in solution suggests that the gallium atom is not sufficiently hindered by the bulky neopentyl groups to preclude dimer formation. The dimeric nature of GaNp_2Cl in solution indicates it is not as weak a Lewis acid as $\text{Ga}(\text{C}_5\text{Me}_5)_2\text{Cl}$, a molecule which is dimeric in the solid state but apparently monomeric in solution.⁷ Our studies indicate that GaNp_2Cl is a relatively weak Lewis acid. The compound forms a stable 1:1 adduct with NMe_3 but not with THF, a slightly weaker Lewis base. The only other gallium compounds which do not form stable adducts with THF are GaMe_3 (Mes=mesityl),⁸ $\text{Ga}(\text{C}_5\text{Me}_5)_2\text{Cl}$ ⁷ and $\text{Ga}(\text{C}_5\text{Me}_5)_3$.⁹ The dihalide derivative, GaNpCl_2 , is a stronger Lewis acid than GaNp_2Cl and forms stable 1:1 adducts with both NMe_3 and THF. The iodide derivative, GaNpI_2 , also forms a 1:1 adduct with THF.

The halide derivatives, GaNp_2X ($\text{X}=\text{Cl}$, Br) and GaNpY_2 ($\text{Y}=\text{Cl}$, I) exhibit characteristic ^1H NMR spectra in benzene solution with the resonances for the methylene protons being downfield of that for the methyl protons for a given compound. Similar observations of the relative chemical shifts of methylene and methyl protons have been reported for benzene solutions of the (trimethylsilyl)methyl halogen derivatives of gallium and indium¹⁰ but not for the (trimethylsilyl)methyl¹¹ or neopentyl⁶ derivatives of aluminum. Other gallium halogen compounds which have methylene and methyl protons in a given substituent also exhibit other patterns. For example, the ^1H NMR

spectrum of $\text{Ga}(\text{i-Bu})_2\text{Cl}$ (neat with sufficient benzene or CH_2Cl_2 for reference)¹² exhibited only one resonance; the lines for the both types of protons were coincident, whereas the line for the methylene protons of GaEt_2Cl (CCl_4 with TMS as reference)¹³ was upfield of that for the methyl line. The significance of these observations is uncertain and will be investigated further as more examples of these types of compounds are characterized.

The ^1H NMR spectrum of a mixture of GaNp_2Cl and GaNpCl_2 in benzene exhibited four resonances at 1.33, 1.23, 0.99 and 0.95 ppm for the four different types of protons in the two molecules. The lines at 1.33 and 0.99 ppm are assigned to the methylene and methyl groups of GaNp_2Cl , respectively, whereas the lines at 1.23 and 0.95 ppm are assigned to the methylene and methyl groups, respectively, of GaNpCl_2 . Although the resonances for the protons of the methyl groups are shifted upfield relative to their positions in the spectra of the pure compounds, the chemical shift of the methylene protons are in excellent agreement with those observed in the spectra of pure GaNp_2Cl and GaNpCl_2 .

The observation that bisneopentylgallium(III) chloride existed as simple dimer in solution prompted a reinvestigation of the synthesis and properties of the (trimethylsilyl)methylgallium(III) chlorides, $\text{Ga}(\text{CH}_2\text{SiMe}_3)_n\text{Cl}_{3-n}$ ($n=1, 2$). The monochloro derivative, $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$, was of particular interest because it had been reported to be a high melting, insoluble solid with a possibly polymeric structure.² In our current studies, $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ has been prepared in 92.5% yield as a colorless, crystalline solid from the reaction of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ and GaCl_3 in a 2:1 mol ratio. An analytically pure sample of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ had a low melting point, 27-29°C. Like GaNpCl_2 , $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ is best handled as a

liquid. In fact, all the properties of $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ are quite similar to those of GaP_2Cl . Bis[(trimethylsilyl)methyl]gallium(III) chloride is very soluble in pentane, benzene and THF. Cryoscopic molecular weight measurements indicate that $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ is dimeric in benzene solution over a concentration range of 0.0730m to 0.0361m. The ^1H NMR spectrum exhibits two resonances at 0.15 and 0.20ppm for the methyl and methylene protons, respectively. The material previously reported to be $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ was prepared in approximately 50% yield by a elimination reaction between $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ and anhydrous HCl .² The product was reported to exhibit a high melting point (159.5-160.0°C) and to be insoluble in pentane and benzene.² In addition to the discrepancies between the melting points and solubility data, the IR spectroscopic data for the two independently prepared samples are also in disagreement. Therefore, it is likely that the previous synthesis² did not yield $\text{Ga}(\text{CH}_2\text{SiMe}_3)_2\text{Cl}$ but perhaps some air-oxidized or hydrolyzed product.

The synthesis and characterization of (trimethylsilyl)-methylgallium(III) dichloride, $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$, has also been reinvestigated. The compound was previously isolated from a ligand redistribution reaction between $\text{Ga}(\text{CH}_2\text{SiMe}_3)_3$ and GaCl_3 in a 1:2 mol ratio in benzene solution.² In the current study, $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$ has also been independently synthesized by the stoichiometric ligand redistribution reaction as a colorless solid in 77.2% yield. It is noteworthy that the melting point of the crude product (48.5-51.5°C) corresponds to the value previously reported² for the purified compound (48-49°C). Upon recrystallization of the crude product from a pentane solution at -40°C, an analytically pure sample of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$ had a melting point of 55.0-56.8°C. The IR spectrum of an analytically pure sample of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$

did not coincide with that previously reported.² The earlier spectroscopic data would be in doubt if it were based on an impure sample of $\text{Ga}(\text{CH}_2\text{SiMe}_3)\text{Cl}_2$.

Acknowledgment. This work was supported in part by the Office of Naval Research. The authors thank Matthew J. Noble, University at Buffalo and Henry J. Gysling, Eastman Kodak Co. for assistance with Lewis acidity studies which used NMe_3 .

References

1. Kuech, T. F. Mat. Sci. Rep. 1987, 2, 3.
2. Beachley, O. T. Jr.; Simmons, R. G. Inorg. Chem. 1980, 19, 1021.
3. Freeland, B. H.; Tuck, D. G. Inorg. Chem. 1976, 15, 475.
4. Shriver, D. F.; Drezdson, M. A., "The Manipulation of Air-Sensitive Compounds", John Wiley & Sons, New York, 1986, p 38.
5. Coates, G. E.; Green, M. L. H.; Wade, K., "Organometallic Compounds", 3rd ed; Metheun: London, 1967; Vol. 1, p 343.
6. Beachley, O. T. Jr.; Victoriano, L. Organometallics 1988, 7, 63.
7. Beachley, O. T. Jr.; Hallock, R. B.; Zhang, H. M.; Atwood, J. L. Organometallics 1985, 4, 1675.
8. Beachley, O. T. Jr.; Churchill, M. R.; Pazik, J. C.; Ziller, J. W. Organometallics 1986, 5, 1814.
9. Beachley, O. T. Jr.; Hallock, R. B. Organometallics 1987, 6, 170.
10. Beachley, O. T. Jr.; Rusinko, R. N. Inorg. Chem. 1979, 18, 1966.
11. Beachley, O. T. Jr.; Tessier-Youngs, C. Organometallics 1983, 2, 796.
12. Kovar, R. A.; Derr, H.; Brandau, D.; Callaway, J. O. Inorg. Chem. 1975, 14, 2809.
13. Schmidbauer, H.; Findeiss, W. Chem. Ber. 1966, 99, 2187.

DL/1113/87/2

TECHNICAL REPORT DISTRIBUTION LIST, GEN

	<u>No. Copies</u>		<u>No. Copies</u>
Office of Naval Research Attn: Code 1113 800 N. Quincy Street Arlington, Virginia 22217-5000	2	Dr. David Young Code 334 NORDA NSTL, Mississippi 39529	1
Dr. Bernard Douda Naval Weapons Support Center Code 50C Crane, Indiana 47522-5050	1	Naval Weapons Center Attn: Dr. Ron Atkins Chemistry Division China Lake, California 93555	1
Naval Civil Engineering Laboratory Attn: Dr. R. W. Drisko, Code L52 Port Hueneme, California 93401	1	Scientific Advisor Commandant of the Marine Corps Code RD-1 Washington, D.C. 20380	1
Defense Technical Information Center Building 5, Cameron Station Alexandria, Virginia 22314	12 high quality	U.S. Army Research Office Attn: CRD-AA-IP P.O. Box 12211 Research Triangle Park, NC 27709	1
DTNSRDC Attn: Dr. H. Singerman Applied Chemistry Division Annapolis, Maryland 21401	1	Mr. John Boyle Materials Branch Naval Ship Engineering Center Philadelphia, Pennsylvania 19112	1
Dr. William Tolles Superintendent Chemistry Division, Code 6100 Naval Research Laboratory Washington, D.C. 20375-5000	1	Naval Ocean Systems Center Attn: Dr. S. Yamamoto Marine Sciences Division San Diego, California 92132	1

END

DATE

FILMED

5-88

DTIC